MA3X786D (MA786WA), MA3X786E (MA786WK)

Silicon epitaxial planar type

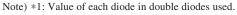
For super high speed switching For small current rectification

Features

- Two MA3X786 (MA786) is contained in one package
- Forward current (Average) $I_{F(AV)} = 100$ mA rectification is possible
- Optimum for high frequency rectification because of its short reverse recovery time t_{rr}
- Low forward voltage V_F and good rectification efficiency

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter		Symbol	Rating	Unit
Reverse voltage		V_R	30	V
Repetitive peak reverse voltage		V_{RRM}	30	V
Peak forward	Single	I_{FM}	300	mA
current	Double *1		200	
Forward current	Single	$I_{F(AV)}$	100	mA
(Average)	Double *1		70	
Non-repetitive peak forward surge current *2		I_{FSM}	1	A
Junction temperature		T _j	125	°C
Storage temperature		T_{stg}	-55 to +125	°C



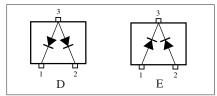
^{*2:} The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

Unit: mm 0.40^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 10⁻¹/_{0.95} 10⁻¹/_{0.95} EIAJ: SC-59 Mini3-Gl Package Unit: mm 0.40^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 0.16^{+0.10}/_{0.05} 1.10⁻¹/_{0.05} 0.10^{+0.10}/_{0.05} 0.10^{+0.10}/_{0.05} 1.10⁻¹/_{0.05} 2.10⁻¹/_{0.05} 1.10⁻¹/_{0.05} 2.10⁻¹/_{0.05} 1.10⁻¹/_{0.05} 1.10⁻¹/_{0.05} 1.10⁻¹/_{0.05} 2.10⁻¹/_{0.05} 2.10⁻¹/_{0.05} 3.10⁻¹/_{0.05} 4.10⁻¹/_{0.05} 5.10⁻¹/_{0.05} 6.10⁻¹/_{0.05} 6.10⁻¹/₀

Marking Symbol

MA3X786D: M3Y
 MA3X786E: M3Z

Internal Connection



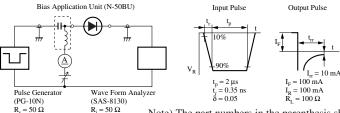
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V _F	$I_F = 100 \text{ mA}$			0.55	V
Reverse current	I_R	$V_R = 30 \text{ V}$			15	μΑ
Terminal capacitance	C _t	$V_R = 0 \text{ V, f} = 1 \text{ MHz}$		20		pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 100 \text{ mA}$		2.0		ns
		$I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$				

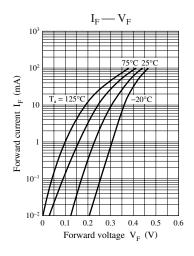
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

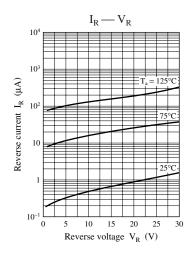
- 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. Absolute frequency of input and output is 250 MHz.

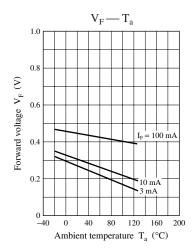
4. *: t_{rr} measurement circuit

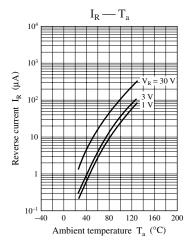


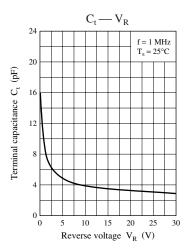
Note) The part numbers in the parenthesis show conventional part number.











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